MilDef T.A.D. Concept 3563











MilDef Tactical Android Device

A fully rugged Android-based mobile device for military operation. With its open architecture and integration capabilities the MilDef T.A.D. opens for several deployment scenarios. The unit are especially designed for military end user, where simplicity and robustness are key. The unit are ideal to be used for dismounted soldier solutions and can withhold the harshest conditions on the battlefield.

Guaranteed performance

All MilDef products come with comprehensive lifecycle sustainment support to ensure your equipment maintains peak performance for many missions to come. We also guarantee the availability of spare parts for 5 years after product end-of-life.

Features

- MediaTek MT8791
- 6" display
- Night Vision mode
- 5G connectivity (inactivable)
- Water submersible and dust resistant (IP67)



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Technical Specif		Security features
Platform	MediaTek MT8791 2x ARM Cortex-A78 @ 2,4 GHz 6x ARM Cortex-A55 @ 2 GHz	Hardware Software
Display	6" HD+ LCD (720 x 1440) Anti reflection coating, Brightness: 500 nits (typical), Capacitive multi touch screen with glove/rain mode, Night vision mode	Power DC-in
Software		
Operating system	Android 13	
Memory		
Storage	6 GB/64 GB (LPDDR4, uCMP) 256 GB SD Card	
Battery		
Battery pack RTC Battery	5000 mAh, field replaceable Yes	
Sound		Other
Audio	HD Audio and Stereo Speakers 2x Microphone	Sensors
Communication		Keypads
GNNS	GPS/GLONASS/Galileo	
NFC	13.56 MHz ISO 1443 A/B,	Size & Weight
	ISO 15693	Dimensions (W x D x H)
PAN	Bluetooth 5.0	Weight
WLAN	802.11 a/b/g/n/ac/ax	Weigiit
WWAN	4G/LTE Network bands: B1, B2, B3, B4, B5, B6, B7, B8, B9, B10, B11, B12, B13, B14, B17, B18, B19, B20, B21, B23, B24, B25, B26, B27, B28, B29,	Environmental S Shock
	B30, B32, B33, B34, B36, B37, B38, B39, B40, B41, B42, B43, B44, B45, B48, B49, B66, B67, B68, B69, B70, B71 5G Network bands (SA/NSA): n1, n2, n3, n5, n7, n8, n12, n13, n14, n17, n18, n20, n24, n25, n26, n28, n29, n30, n34, n38, n39, n40, n41, n48, n50, n51, n77, n78, n79	Vibration IP High temperature operating High temperature storage Low temperature
Ethernet	Dual simultaneous Ethernet via USB hub through USB-C port	operating
Ports		Low temperature
Audio	3.5 mm Earphone jack	storage
USB	USB 3.2 Gen 2 Type C with support of thumbscrew, Fast Charge/OTG	Standards
SIM	RNDIS support 2x Nano SIM	CE / FCC / UKCA REACH/RoHS2.0
Camera		Environment
Front	8 MP	Warranty
Back	13 MP Auto focus	Warranty

occurry reatures	
Hardware	TBD
Software	Verified boot, Military grade File-
	Base Encryption.
_	More details available.
Power	1107 7
DC-in	USB Type C with fast charge OTG output voltage: 5.05 V
	(default)
	OTG output voltage range:
	4.425 ~ 5.825 V, 50 mV /step
	OTG output current: 1.3 A
	(default) OTG output current range:
	0.5 A, 0,7 A, 1.1 A, 1.3 A, 1.8
	A, 2.1 A, 2.4 A
	Charging available via pogo pins
Other	
Sensors	Ambient, Gyroscope, Proximity,
	Accelerometer
Keypads	x2 Volume, x1 Power, x1 Night
	Vision, x2 Function buttons
Size & Weight	
Dimensions	TBD
(W x D x H)	TDD / 450 COO ~ / 0 00
Weight	TBD (~450 – 600 g / 0.99 –
	1.32 lb.)
Environmental S	
Environmental Shock	Specification MIL-STD-810H, Method 516.8,
	Specification MIL-STD-810H, Method 516.8, Procedure IV Transit drop 1.6 m
	Specification MIL-STD-810H, Method 516.8,
	Specification MIL-STD-810H, Method 516.8, Procedure IV Transit drop 1.6 m
Shock	MIL-STD-810H, Method 516.8, Procedure IV Transit drop 1.6 m (5.25 ft)
Shock Vibration	MIL-STD-810H, Method 516.8, Procedure IV Transit drop 1.6 m (5.25 ft) MIL-STD-810H, Method 514.8
Shock Vibration IP High temperature	MIL-STD-810H, Method 516.8, Procedure IV Transit drop 1.6 m (5.25 ft) MIL-STD-810H, Method 514.8 IP67 without I/O cover
Shock Vibration IP High temperature operating	MIL-STD-810H, Method 516.8, Procedure IV Transit drop 1.6 m (5.25 ft) MIL-STD-810H, Method 514.8 IP67 without I/O cover MIL-STD-810H, Method 501.5 Procedure II, +55 °C (+131 °F)
Shock Vibration IP High temperature operating High	MIL-STD-810H, Method 516.8, Procedure IV Transit drop 1.6 m (5.25 ft) MIL-STD-810H, Method 514.8 IP67 without I/O cover MIL-STD-810H, Method 501.5 Procedure II, +55 °C (+131 °F)
Shock Vibration IP High temperature operating High temperature	MIL-STD-810H, Method 516.8, Procedure IV Transit drop 1.6 m (5.25 ft) MIL-STD-810H, Method 514.8 IP67 without I/O cover MIL-STD-810H, Method 501.5 Procedure II, +55 °C (+131 °F)
Shock Vibration IP High temperature operating High temperature storage	MIL-STD-810H, Method 516.8, Procedure IV Transit drop 1.6 m (5.25 ft) MIL-STD-810H, Method 514.8 IP67 without I/O cover MIL-STD-810H, Method 501.5 Procedure II, +55 °C (+131 °F) MIL-STD-810H, Method 501.5, Procedure I, +70 °C (+158 °F)
Shock Vibration IP High temperature operating High temperature	MIL-STD-810H, Method 516.8, Procedure IV Transit drop 1.6 m (5.25 ft) MIL-STD-810H, Method 514.8 IP67 without I/O cover MIL-STD-810H, Method 501.5 Procedure II, +55 °C (+131 °F) MIL-STD-810H, Method 501.5, Procedure I, +70 °C (+158 °F) MIL-STD-810H, Method 502.5, Procedure II (battery mode), -20
Shock Vibration IP High temperature operating High temperature storage Low temperature	MIL-STD-810H, Method 516.8, Procedure IV Transit drop 1.6 m (5.25 ft) MIL-STD-810H, Method 514.8 IP67 without I/O cover MIL-STD-810H, Method 501.5 Procedure II, +55 °C (+131 °F) MIL-STD-810H, Method 501.5, Procedure I, +70 °C (+158 °F) MIL-STD-810H, Method 502.5,
Shock Vibration IP High temperature operating High temperature storage Low temperature operating	MIL-STD-810H, Method 516.8, Procedure IV Transit drop 1.6 m (5.25 ft) MIL-STD-810H, Method 514.8 IP67 without I/O cover MIL-STD-810H, Method 501.5 Procedure II, +55 °C (+131 °F) MIL-STD-810H, Method 501.5, Procedure I, +70 °C (+158 °F) MIL-STD-810H, Method 502.5, Procedure II (battery mode), -20 °C (-4 °F)
Shock Vibration IP High temperature operating High temperature storage Low temperature	MIL-STD-810H, Method 516.8, Procedure IV Transit drop 1.6 m (5.25 ft) MIL-STD-810H, Method 514.8 IP67 without I/O cover MIL-STD-810H, Method 501.5 Procedure II, +55 °C (+131 °F) MIL-STD-810H, Method 501.5, Procedure I, +70 °C (+158 °F) MIL-STD-810H, Method 502.5, Procedure II (battery mode), -20
Shock Vibration IP High temperature operating High temperature storage Low temperature operating Low temperature	MIL-STD-810H, Method 516.8, Procedure IV Transit drop 1.6 m (5.25 ft) MIL-STD-810H, Method 514.8 IP67 without I/O cover MIL-STD-810H, Method 501.5 Procedure II, +55 °C (+131 °F) MIL-STD-810H, Method 501.5, Procedure I, +70 °C (+158 °F) MIL-STD-810H, Method 502.5, Procedure II (battery mode), -20 °C (-4 °F) MIL-STD-810H, Method 502.5,
Shock Vibration IP High temperature operating High temperature storage Low temperature operating Low temperature storage	MIL-STD-810H, Method 516.8, Procedure IV Transit drop 1.6 m (5.25 ft) MIL-STD-810H, Method 514.8 IP67 without I/O cover MIL-STD-810H, Method 501.5 Procedure II, +55 °C (+131 °F) MIL-STD-810H, Method 501.5, Procedure I, +70 °C (+158 °F) MIL-STD-810H, Method 502.5, Procedure II (battery mode), -20 °C (-4 °F) MIL-STD-810H, Method 502.5,
Shock Vibration IP High temperature operating High temperature storage Low temperature operating Low temperature storage Standards	MIL-STD-810H, Method 516.8, Procedure IV Transit drop 1.6 m (5.25 ft) MIL-STD-810H, Method 514.8 IP67 without I/O cover MIL-STD-810H, Method 501.5 Procedure II, +55 °C (+131 °F) MIL-STD-810H, Method 501.5, Procedure I, +70 °C (+158 °F) MIL-STD-810H, Method 502.5, Procedure II (battery mode), -20 °C (-4 °F) MIL-STD-810H, Method 502.5, Procedure I, -30 °C (-40 °F)
Shock Vibration IP High temperature operating High temperature storage Low temperature operating Low temperature storage Standards CE / FCC / UKCA	MIL-STD-810H, Method 516.8, Procedure IV Transit drop 1.6 m (5.25 ft) MIL-STD-810H, Method 514.8 IP67 without I/O cover MIL-STD-810H, Method 501.5 Procedure II, +55 °C (+131 °F) MIL-STD-810H, Method 501.5, Procedure I, +70 °C (+158 °F) MIL-STD-810H, Method 502.5, Procedure II (battery mode), -20 °C (-4 °F) MIL-STD-810H, Method 502.5, Procedure I, -30 °C (-40 °F)
Shock Vibration IP High temperature operating High temperature storage Low temperature operating Low temperature storage Standards CE / FCC / UKCA REACH/ROHS2.0 Environment	MIL-STD-810H, Method 516.8, Procedure IV Transit drop 1.6 m (5.25 ft) MIL-STD-810H, Method 514.8 IP67 without I/O cover MIL-STD-810H, Method 501.5 Procedure II, +55 °C (+131 °F) MIL-STD-810H, Method 501.5, Procedure I, +70 °C (+158 °F) MIL-STD-810H, Method 502.5, Procedure II (battery mode), -20 °C (-4 °F) MIL-STD-810H, Method 502.5, Procedure I, -30 °C (-40 °F) Yes / Yes / Yes Yes / Yes
Shock Vibration IP High temperature operating High temperature storage Low temperature operating Low temperature operating Standards CE / FCC / UKCA REACH/ROHS2.0 Environment Warranty	MIL-STD-810H, Method 516.8, Procedure IV Transit drop 1.6 m (5.25 ft) MIL-STD-810H, Method 514.8 IP67 without I/O cover MIL-STD-810H, Method 501.5 Procedure II, +55 °C (+131 °F) MIL-STD-810H, Method 501.5, Procedure I, +70 °C (+158 °F) MIL-STD-810H, Method 502.5, Procedure II (battery mode), -20 °C (-4 °F) MIL-STD-810H, Method 502.5, Procedure I, -30 °C (-40 °F) Yes / Yes / Yes Yes / Yes MIL-STD-810H, IP67
Shock Vibration IP High temperature operating High temperature storage Low temperature operating Low temperature storage Standards CE / FCC / UKCA REACH/ROHS2.0 Environment	MIL-STD-810H, Method 516.8, Procedure IV Transit drop 1.6 m (5.25 ft) MIL-STD-810H, Method 514.8 IP67 without I/O cover MIL-STD-810H, Method 501.5 Procedure II, +55 °C (+131 °F) MIL-STD-810H, Method 501.5, Procedure I, +70 °C (+158 °F) MIL-STD-810H, Method 502.5, Procedure II (battery mode), -20 °C (-4 °F) MIL-STD-810H, Method 502.5, Procedure I, -30 °C (-40 °F) Yes / Yes / Yes Yes / Yes

Cables, Chest mount for PALS/MOLLE equipment,

Comfortable Wearable Batteries



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